

# Highly Integrated Offline Current Mode PWM Power Switch

#### **FEATURES**

- Integrated with 650V Power MOSFET
- ±1% CV Regulation
- Less than 75mW Standby Power
- Fixed 65KHz Switching Frequency
- Green Mode and Burst Mode Control
- Very Low Startup and Operation Current
- Built-in Frequency Shuffling to Reduce
   EMI
- Built-in Current Mode Control with
  Internal Slope Compensation
- Built-in Protections with Auto Recovery:
  - VDD Under Voltage Lockout (UVLO)
  - VDD Over Voltage Protection (OVP)
  - On-Chip Thermal Shutdown (OTP)
  - Cycle-by-Cycle Current Limiting
  - Over Load Protection (OLP)
  - CS Pin Float Protection
- Available with DIP-7/DIP8 Package

#### **GENERAL DESCRIPTION**

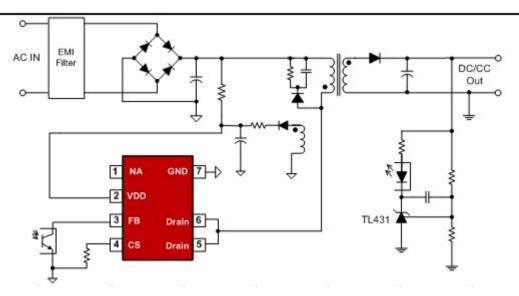
DP2358B is a high performance current mode PWM power switch for offline flyback converter applications.

In DP2358B, PWM switching frequency with shuffling is fixed to 65KHz and is trimmed to tight range. The IC has built-in green and burst mode control for light and zero loadings, which can achieve less than 75mW standby power.

DP2358B integrates functions and protections of Under Voltage Lockout (UVLO), VDD over Voltage Protection (VDD OVP), Cycle-by-cycle Current Limiting (OCP), Over Load Protection (OLP), On-Chip Thermal Shutdown (OTP), Soft Start, VDD Clamping and CS Pin Float Protection, etc.

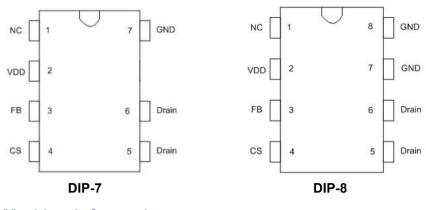
#### **APPLICATIONS**

- Power Adapter
- General Switch Mode Power Supply
- **TYPICAL APPLICATION CIRCUIT**





# **Pin Configuration**



# Marking Information



## **Pin Description**

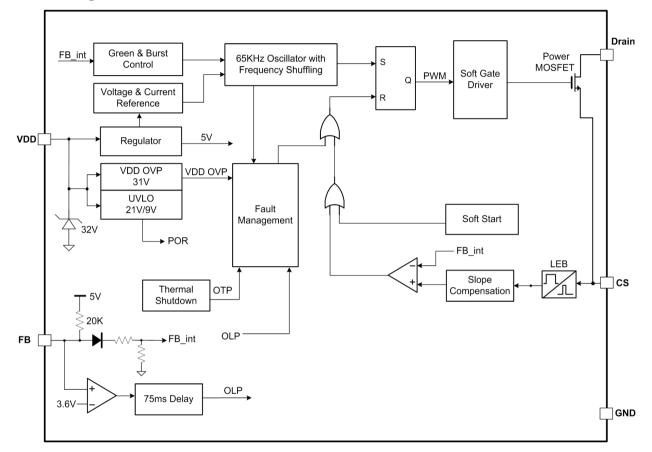
Pin Number	Pin Number	I/O	Description	
1	NA		Un-connection Pin. Left float in the practical design	
2	VDD	Р	IC power supply pin	
3	FB	I	Feedback pin. The loop regulation is achieved by connecting a photo-coupler to this pin. PWM duty cycle is determined by this pin voltage and the current sense signal at Pin 4	
4	CS	I	Current Sense Input Pin	
5,6	Drain	0	The Power MOSFET Drain	
7,8	GND	Р	The Ground of the IC	



## **Ordering Information**

Part Number	Description		
DP2358B	DIP-7/DIP8, Pb free, 50Pcs/Tube		

## **Block Diagram**





## Absolute Maximum Ratings (Note 1)

Parameter	Value	Unit
VDD DC Supply Voltage	30	V
VDD DC Clamp Current	10	mA
Drain Pin	-0.3 to 600	V
FB, CS Voltage Range	-0.3 to 7	V
Package Thermal ResistanceJunction to Ambient(DIP-7)	105	°C/W
Maximum Junction Temperature	175	°C
Storage Temperature Range	-65 to 150	°C
Lead Temperature (Soldering, 10sec.)	260	°C
ESD Capability, HBM (Human Body Model)	4	kV
ESD Capability, MM (Machine Model)	500	V

## **Recommended Operation Conditions (Note 2)**

Parameter	Value	Unit	
Supply Voltage, VDD	10 to 26	V	
Operating Ambient Temperature	-40 to 85	°C	

## Electrical Characteristics (Ta = 25°C, VIN=12V, if not otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур.	Мах	Unit		
Supply Volt	Supply Voltage Section(VDD Pin)							
I <sub>VDD_st</sub>	Start-up current into VDD pin			2	20	uA		
I <sub>VDD_Op</sub>	Operation Current	V <sub>FB</sub> =3V		1.2	2	mA		
IVDD_standby	Standby Current			0.6	1	mA		
$V_{\text{DD}\_\text{ON}}$	VDD Under Voltage Lockout Exit		19	21	21.5	V		
$V_{DD_OFF}$	VDD Under Voltage Lockout Enter		8	9	10	V		
V <sub>DD_OVP</sub>	VDD OVP Threshold		29	31	33	V		
$V_{DD\_Clamp}$	VDD Zener Clamp Voltage	I(V <sub>DD</sub> )=7 mA	33	35	37	V		
Feedback Ir	put Section (FB Pin)							
V <sub>FB_Open</sub>	FB Open Voltage			5.9		V		
I <sub>FB_Short</sub>	FB Short Circuit Current	Short FB Pin to GND, Measure Current		0.3		mA		
$Z_{FB_{IN}}$	FB Input Impedance			20		KΩ		
Acs	PWM Gain	$\Delta V_{FB} / \Delta V_{CS}$		2.0		V/V		



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V <sub>skip</sub>	FB Under Voltage PWM Clock is OFF			1.0		V	
V <sub>TH_OLP</sub>	Power Limiting FB Threshold Voltage			3.6		V	
T <sub>D_OLP</sub>	Power Limiting Debounce Time	SEL Pin is floating		75		ms	
Current Sen	se Input Section (CS Pin)						
T <sub>LEB</sub>	CS Input Leading Edge Blanking Time			250		ns	
V <sub>cs(max)</sub>	Current limiting threshold		0.97	1.0	1.03	V	
T <sub>D_OC</sub>	Over Current Detection and Control Delay			70		ns	
Oscillator Se	ection						
Fosc	Normal Oscillation Frequency		60	65	70	KHz	
ΔF(shuffle) /F <sub>osc</sub>	Frequency Shuffling Range		-4		4	%	
T(shuffle)	Frequency Shuffling Period			32		ms	
D <sub>MAX</sub>	Maximum Switching Duty Cycle			66.7		%	
F <sub>Bust</sub>	Burst Mode Base Frequency			22		KHz	
On-Chip The	On-Chip Thermal Shutdown						
T <sub>SD</sub>	Thermal Shutdown	(Note 3)		165		°C	
T <sub>RC</sub>	Thermal Recovery	(Note 3)		140		°C	
Power MOS	Power MOSFET Section (Drain Pin)						
VBR	Power MOSFET Drain Source Breakdown Voltage		650			V	
R <sub>dson</sub>	Static Drain-Source On Resistance			5		Ω	

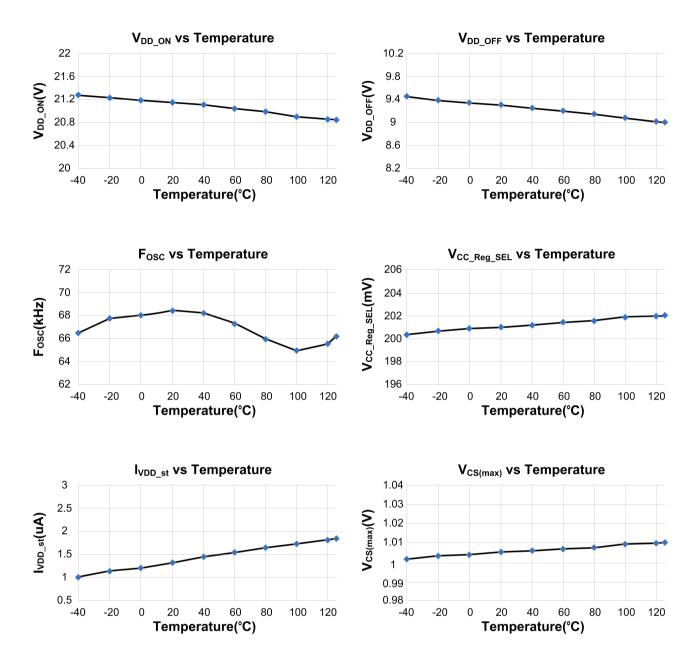
**Note1.** Stresses listed as the above "Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to maximum rating conditions for extended periods may remain possibility to affect device reliability.

Note2. The device is not guaranteed to function outside its operating conditions.

Note3. Guaranteed by the Design.



## **Characterization Plots**





### **Operation Description**

DP2358B is a high performance current mode PWM power switch for offline flyback converter, motor driver power supply, and adapter applications.

#### • System Start-Up Operation and IC Operation Current

Before the IC starts to work, it consumes only startup current (typically 2uA) which allows a large value startup resistor to be used to minimize the power loss and the current flowing through the resistor charges the VDD hold-up startup capacitor from the high voltage DC bus. When VDD reaches turn on threshold VDD ON (typical 21V), DP2358B begins switching and the IC operation current is increased to be 1mA (typical). The hold-up capacitor continues to supply VDD before the auxiliary winding of the transformer takes the control of VDD voltage. When the IC enters into burst mode, the IC operation current will decrease further, thus less than 75mW standby power.

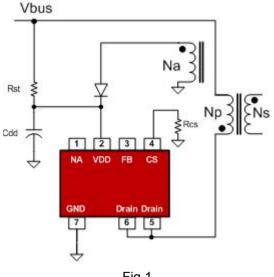


Fig.1

• Oscillator with Frequency Shuffling

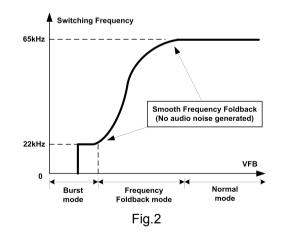
PWM switching frequency in DP2358B is fixed to 65KHz and is trimmed to tight range. To improve

#### • Green Mode Operation

Since the main power dissipation at light/zero load in a switching mode power supply is from the switching loss which is proportional to the PWM switching frequency. To meet green mode requirement, it is necessary to reduce the switching cycles under such conditions either by skipping some switching pulses or by reducing the switching frequency.

#### Smooth Frequency Foldback

In DP2358B, a Proprietary "Smooth Frequency Foldback" function is integrated to foldback the PWM switching frequency when the loading is light. Compared to the other frequency reduction implementations, this technique can reduce the PWM frequency smoothly without audible noise.

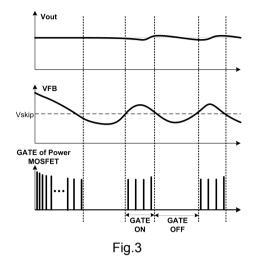


#### **Burst Mode Control**

When the loading is very small, the system enters into burst mode. When VFB drops below Vskip, DP2358B will stop switching and output voltage starts to drop (as shown in Fig.3), which causes the VFB to rise. Once VFB rises above Vskip, switching resumes. Burst mode control alternately



enables and disables switching, thereby reducing switching loss in standby mode.



#### • Built-in Slope Compensation

In the conventional application, the problem of the stability is a critical issue for current mode controlling, when it operates in higher than 50% of the duty-cycle. In DP2358B the slope compensation circuit is integrated by adding voltage ramp onto the current sense input voltage for PWM generation. This greatly improves the close loop stability at CCM and prevents the sub-harmonic oscillation and thus reduces the output ripple voltage.

#### • Leading Edge Blanking (LEB)

Each time the power MOSFET is switched on, a turn-on spike occurs across the sensing resistor. The spike is caused by primary side capacitance and secondary side rectifier reverse recovery. To avoid premature termination of the switching pulse, an internal leading edge blanking circuit is built in. During this blanking period (250ns, typical), the PWM comparator is disabled and cannot switch off the gate driver.

#### • On Chip Thermal Shutdown (OTP)

When the IC temperature is over 165 °C, the IC shuts down. Only when the IC temperature drops to 140 °C, IC will restart.

#### • Soft Start

DP2358B features an internal 2ms (typical) soft start that slowly increases the threshold of cycleby-cycle current limiting comparator during startup sequence. It helps to prevent transformer saturation and reduce the stress on the secondary diode during startup. Every restart attempt is followed by a soft start activation.

#### • Constant Power Limiting

A proprietary "Constant Power Limiting" block is integrated to achieve constant maximum output power capability over universal AC input range. Based on the duty cycle information, the IC generates OCP threshold according to a proprietary analog algorithm.

#### • Over Load Protection (OLP)

If over load occurs, a fault is detected. If this fault is present for more than 75ms (typical), the protection will be triggered, the IC will experience an auto-recovery mode protection as mentioned above. The 75ms delay time is to prevent the false trigger from the power-on and turn-off transient.

# • VDD Over Voltage Protection (OVP) and Zener Clamp

When VDD voltage is higher than 31V (typical), the IC will stop switching. This will cause VDD fall down to be lower than  $V_{DD_OFF}$  (typical 9V) and then the system will restart up again. An internal 35V (typical) zener clamp is integrated to prevent the IC from damage.

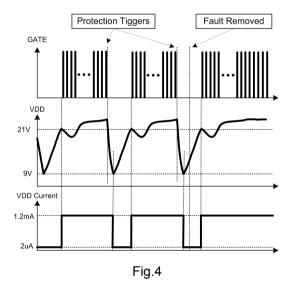
#### • CS Pin Float Protection

When VDD voltage is higher than  $V_{DD_ON}$  (21V typical), IC firstly starts to check whether CS pin is floated. If CS pin is floated, switching is blocked and IC enters auto-recovery mode; otherwise, normal work begins. With this protection, system stability is enhanced.



# Auto Recovery Mode Protection

As shown in Fig.4, once a fault condition is detected, PWM switching will stop. This will cause VDD to fall because no power is delivered form the auxiliary winding. When VDD falls to  $V_{DD_OFF}$  (typical 9V), the protection is reset and the operating current reduces to the startup current, which causes VDD to rise. The system begins switching when VDD reaches to  $V_{DD_ON}$  (typical 21V). However, if the fault still exists, the system will experience the above mentioned process. If the fault has gone, the system resumes normal operation. In this manner, the auto restart can alternatively enable and disable the switching until the fault condition is disappeared.



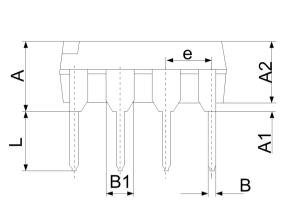
#### • Soft Totem-Pole Gate Driver

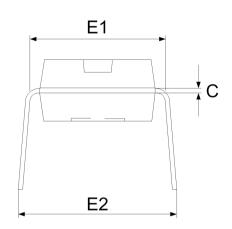
DP2358B has a soft totem-pole gate driver with optimized EMI performance. An internal gate

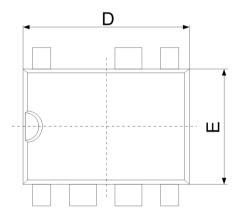
clamp is added for power MOSFET gate protection when high VDD input.



## Package Dimension







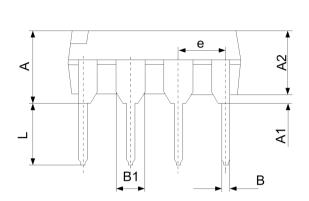
Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Мах	Min	Мах	
А	3.710	4.310	0.146	0.170	
A1	0.510		0.020		
A2	3.200	3.600	0.126	0.142	
В	0.380	0.570	0.015	0.022	
B1	1.524(BSC)		0.060(BSC)		
С	0.204	0.360	0.008	0.014	
D	9.000	9.400	0.354	0.370	
E	6.200	6.600	0.244	0.260	
E1	7.320	7.920	0.288	0.312	
е	2.540(BSC)		0.100(BSC)		
L	3.000	3.600	0.118	0.142	
E2	8.400	9.000	0.331	0.354	

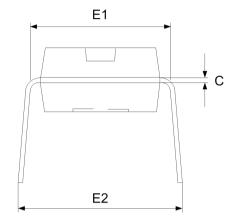
DIP-7

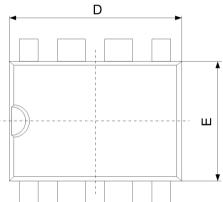


Package Dimension









Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	3.710	5.334	0.146	0.210	
A1	0.381		0.015		
A2	3.175	3.600	0.125	0.142	
В	0.350	0.650	0.014	0.026	
B1	1.524 (	BSC)	0.06 (BSC)		
С	0.200	0.360	0.008	0.014	
D	9.000	10.160	0.354	0.400	
E	6.200	6.600	0.244	0.260	
E1	7.320	7.920	0.288	0.312	
е	2.540 (BSC)		0.1 (BSC)		
L	2.921	3.810	0.115	0.150	
E2	8.200	9.525	0.323	0.375	